# **EVHF920-S-00D**



85VAC/60Hz~350VAC/50Hz 13.5V/0.3A;8V/50mA;8V/50mA Off-line Switching Regulator

### DESCRIPTION

HF920 is a flyback regulator with a monolithic 900V MOSFET. HF920 provides excellent power regulation in AC-DC applications that require high reliability. The switching frequency can be programmed with a single resistor. Also a special frequency doubling mode, designed for strong magnetizing application, can be enabled through a simple external setup.

EVHF920-S-00D evaluation board is specially designed for a better EMC performance with very few EMI filters, which provides reference to effective PCB design for the customer. It features an off-line wide input voltage (85VAC~350VAC) with triple outputs (13.5V/300mA, 8V/50mA, 8V/50mA), and is very suitable for power meter application with the need of three isolated power supplies.

EVHF920-S-00D can meets EN55022 conducted EMI requirements easily with frequency jittering function, as well as CISPR22 RE class B with the proper transformer design. It offers a full suite of protective features such as over-temperature protection. VCC under-voltage lockout, over-voltage protection, over-load protection and short-circuit protection.

#### **ELECTRICAL SPECIFICATION**

Parameter	Symbol	Value	Units
Input Voltage	V <sub>IN</sub>	85 to 350	VAC
Output Voltage1	V <sub>OUT1</sub>	13.5	V
Output Current1	I <sub>OUT1</sub>	300	mA
Output Voltage2	V <sub>OUT2</sub>	8	V
Output Current2	I <sub>OUT2</sub>	50	mA
Output Voltage3	Vouтз	8	V
Output Current3	l <sub>оитз</sub>	50	mA

### **FEATURES**

- Wide input voltage (85VAC~350VAC)
- Triple isolated output power supplies
- Fixed switching frequency, programmable up to 150kHz
- Frequency doubling operation mode
- **Excellent EMC performance**
- External input PRO pin protection with hysteresis and auto-restart recovery
- Over Temperature Protection
- Over Voltage Protection on VCC
- Time-based Over Load Protection
- **Short Circuit Protection**

#### **APPLICATIONS**

- E-Meters
- Industrial controls
- Large appliances

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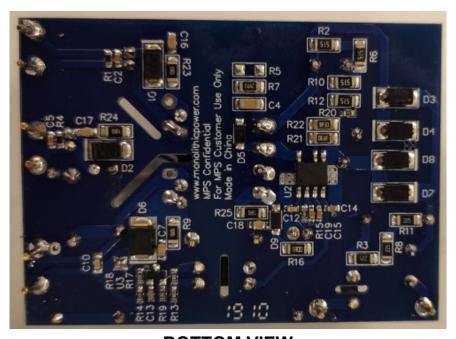
Warning: Although this board is designed to satisfy safety requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.



# **EVHF920-S-00D EVALUATION BOARD**



**TOP VIEW** 



# **BOTTOM VIEW**

(L x W x H) 65mm x 47mm x 22mm

Board Number	MPS IC Number
EVHF920-S-00D	HF920GSE



### **EVALUATION BOARD SCHEMATIC**

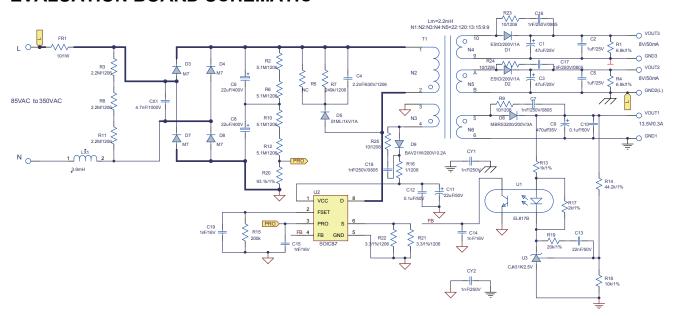


Figure 1: Schematic

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# **EVHF920-S-00D BILL OF MATERIALS**

Qty	Ref	Value	Description	Package	Manufacturer	Manufactuer_P/N
2	C1,C3	47µF	Electrolytic Capacitor;25V	DIP	Jianghai	CD28L-25V47
2	C2,C5	1µF	Ceramic Capacitor;25V;X7R	0603	Murata	GRM188R71E2105KA12D
1	C4	2.2nF	Ceramic Capacitor;630V;X7R	1206	Murata	GRM31BR72J222KW01L
2	C6,C8	22µF	Electroytic Cacitor;400V	DIP	Rubycon	400PX22MEFC12.5X20
4	C7,C1 6,C17, C18	1nF	Ceramic Capacitor;250V;X7R	0805	Murata	GRM21AR72E102KW01D
1	C9	470µF	Ceramic Capacitor;35V	DIP	Jianghai	CD263-35V470
2	C10,C 12	100nF	Ceramic Capacitor;50V	0603	Wurth	885012206095
1	C11	22µF	Electrolytic Capacitor;50V	DIP	Rubycon	50YXM22MEFC5*11
1	C13	22nF	Ceramic Capacitor;50V	0603	Murata	GRM188R71H223KA01D
3	C14,C 15,C19	1nF	Ceramic Capacitor;16V	0603	Wurth	8.85012E+11
1	CX1	4.7nF	X Capacitor 1000V	DIP	法拉	MMKP82-1000V-472P1
2	CY1,C Y2	1nF	Y Capacitor;250V;20%	DIP	Hongke	JNK09E102MY02N
2	D1,D2	ES1D	Schottky Diode;200V;1A	SMA	Diodes	Taiwan
4	D3, D4, D7,D8	M7	Diode;1000V;1A	SMA	Diodes	Toshiba
1	D5	S1ML	Diode;1000V;1A;	SOD123	Diodes	Taiwan
1	D6	MBRS32 00T3G	Schottky Diode;200V;3A	SMB	Onsemi	MBRS3200TS3G
1	D9	BAV21W	Diode;200V;0.2A;	SOD123	Diodes	BAV21W-7-F
1	LX1	7447452 392	3.9mH	DIP	Wurth	7447452392
1	FR1	10	Fuse Resistor;5%;1/2W	DIP	СТС	FKN1WSJT-52-10R
2	R1,R4	6.8k	Film Resistor;1%	0603	Yageo	RC0603FR-076K8L
4	R2, R6, R10, R12	5.1M	Film Resistor;5%;1/4W	1206	Yageo	RI1206L515JT
3	R3, R8, R11	2.2M	Film Resistor;5%;1/4W	1206	Royalohm	1206J0225T5E
1	R7	249k	Film Resistor;5%;1/4W	1206	Yageo	RC1206FR-07249KL
4	R9,R2 3,R24, R25	10	Film Resistor;1%;1/4W	1206	Yageo	RC1206FR-0710RL



# **EVHF920-S-00D BILL OF MATERIALS** (continued)

Qty	Ref	Value	Description	Package	Manufacturer	Manufactuer_P/N
1	R13	1k	Film Resistor;1%	0603	Yageo	RC0603FR-071KL
1	R14	44.2k	Film Resistor;1%	0603	Yageo	RC0603FR-0744K2L
1	R15	210k	Film Resistor;1%	0603	Yageo	RC0603FR-07210KL
1	R16	1	Film Resistor;1%	1206	Yageo	RC1206FR-071RL
1	R17	2k	Film Resistor;1%	0603	Yageo	RC0603FR-072KL
1	R18	10k	Film Resistor;1%	0603	Yageo	RC0603FR-0710KL
1	R19	20k	Film Resistor;1%	0603	Yageo	RC0603FR-0720KL
1	R20	93.1k	Film Resistor;1%	0603	Yageo	RC0603FR-0793K1L
2	R21,R 22	3.3	Film Resistor;1%;1/4W	1206	Yageo	RC1206FR-073R3L
1	U2	HF920G SE	Flyback regulator with 900V integrated MOS	SOIC8-7 A	MPS	HF920GSE
1	U1	EL817B	Photocoupler;1-Chan nel	DIP	Everlight	EL817B
1	U3	CJ431	2.5V voltage reference	SOT23	Diodes	CJ431
	8	L,N,VOU T1, VOUT2, GND1,G ND2,Vout 3,GND3	Connector	1.0mm		
	1	JP1		28mm		
	1	JP2		22.6mm		
	1	Transfor mer		EE16 FX0553		

### Notes:

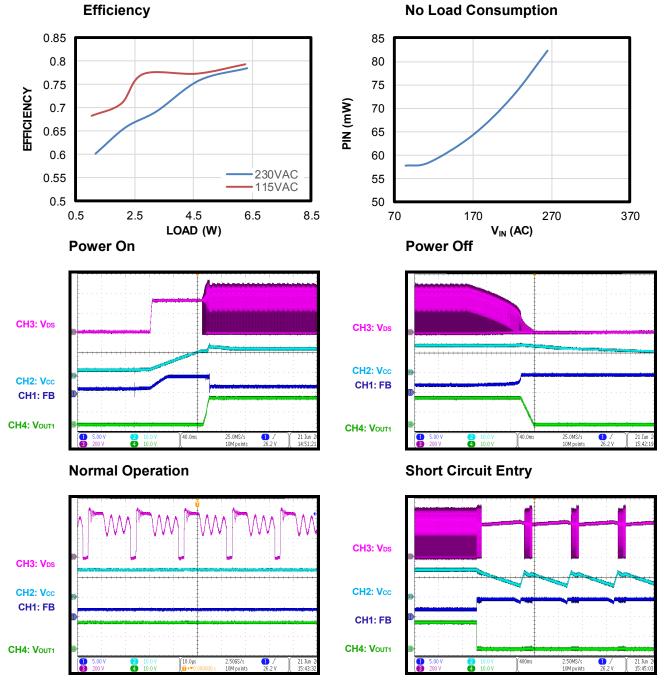
<sup>1)</sup> Emei transformer sample request please login on website: www.emeigroup.com



### **EVB TEST RESULTS**

Performance waveforms are tested on the evaluation board.

VIN = 230VAC, VOUT1 = 13.5V, IOUT1 = 300mA, VOUT2 = VOUT3 = 8V, IOUT2 = IOUT3 = 50mA, TA = 25°C, unless otherwise noted.





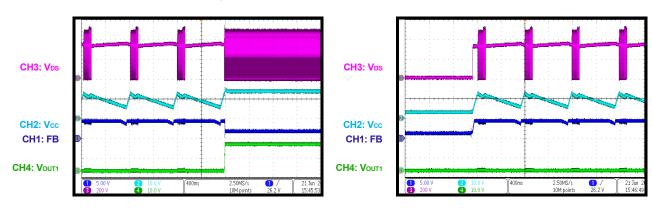
### TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Performance waveforms are tested on the evaluation board.

VIN = 230VAC, VOUT1 = 13.5V, IOUT1 = 300mA, VOUT2 = VOUT3=8V, IOUT2 = IOUT3 = 50mA, TA = 25°C, unless otherwise noted.

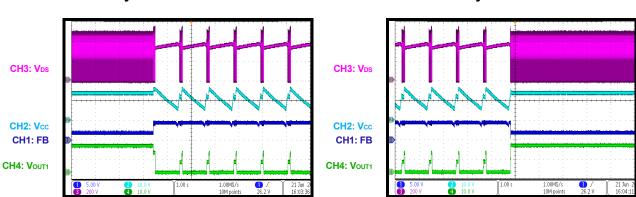


#### **Short Circuit Power On**



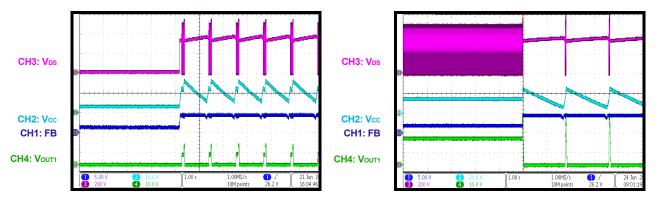
### **OLP Entry**

## **OLP Recovery**



#### **OLP Power On**

### **OVP Entry**

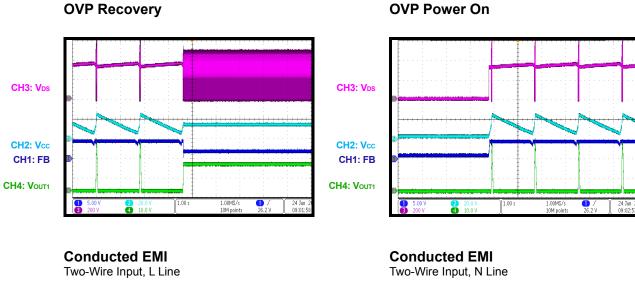


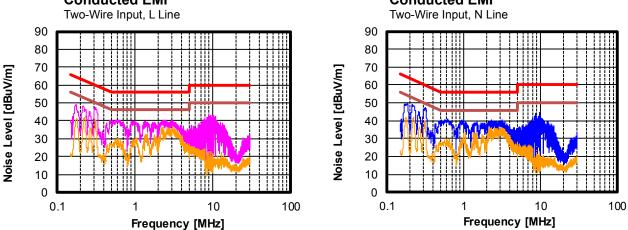


### TYPICAL PERFORMANCE CHARACTERISTICS (continued)

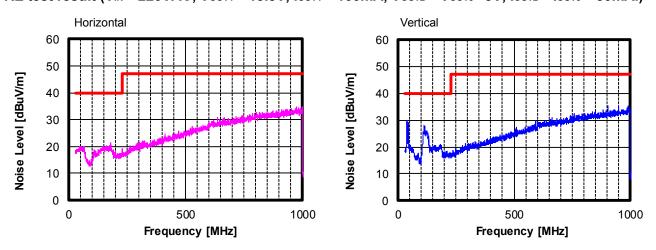
Performance waveforms are tested on the evaluation board.

VIN = 230VAC, VOUT1 = 13.5V, IOUT1 = 300mA, VOUT2 = VOUT3=8V, IOUT2 = IOUT3 = 50mA, TA = 25°C, unless otherwise noted.





RE test result (VIN = 220VAC, VOUT1 = 13.5V, IOUT1 = 100mA, VOUT2 = VOUT3 = 8V, IOUT2 = IOUT3 = 50mA.)





# **PCB LAYOUT (DUAL-SIDED)**

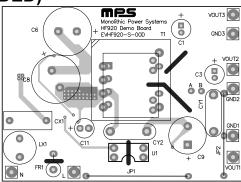


Figure 2:Top Layer

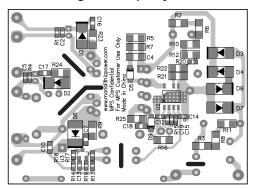


Figure 3: Bottom Layer

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### TRANSFORMER SPECIFICATION

### **Electrical Diagram**

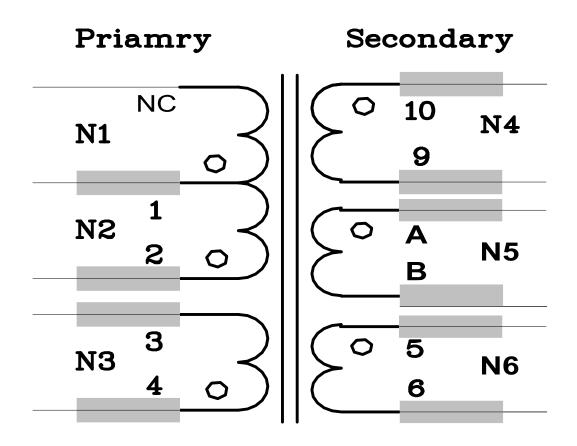


Figure 4—Transformer Electrical Diagram

#### Notes:

- All winding terminals are added tube; 1.
- N5 is flying out from the bobbin. Terminal A is labeled with black and terminal B is labeled with white; 2.
- Remove Pin7 and Pin8; 3.
- Varnish the transformer.



### **Winding Diagram**

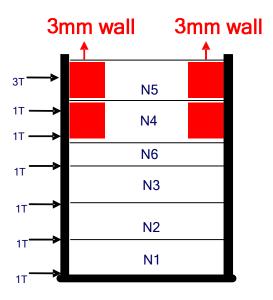


Figure 5—Winding Diagram



### **Winding Order**

Winding No.	Tape Layer No.	Start & End	Magnet Wire φ(mm)	Turns
N1	1	1—> NC	0.18mm*2	22
N2	1	2—〉1	0.15mm*1	120
N3	1	4—⟩ 3	0.18mm*3	13
N6	1	5—⟩ 6	0.3mm*1 TIW	15
N4	1	10—〉9	0.16mm*1 TIW	9
N5	1	A—⟩ B	0.16mm*1 TIW	9

Electrical Specifications

	60 second, 60Hz, from PRI. to SEC.	4500VAC
Electrical Strength	60 second, 60Hz, from N4. to N6	4500VAC
	60 second, 60Hz, from PRI. to CORE	500VAC
	60 second, 60Hz, from N5. to CORE	2500VAC
	Pins 1-2, all other windings open,	
Primary Inductance	measured at	2.2mH±5%
	60kHz, 0.1VRMS	

### **Materials**

Item	Description
1	Core: EF16, UI=2300±25%, AL=1100nH/N <sup>2</sup> ±25% UNGAPPED
2	Bobbin: EF16 Vertical, 4+6PIN 1SECT T-H
3	Wire: Φ0.15mm, 2UEW, Class B
4	Wire: Φ0.18mm, 2UEW, Class B
5	Triple Insulation Wire: Φ0.30mm TIW
6	Triple Insulation Wire: Φ0.16mm TIW
7	Tape: 8.5mm(W) ×0.06mm(TH)
8	Tube: #26 BLACK; #26 CLEAR; #30 CLEAR; #23 CLEAR
9	Varnish: JOHN C. DOLPH CO, BC-346A or equivalent
10	Solder Bar: CHEN NAN: SN99.5/Cu0.5 or equivalent



#### CIRCUIT DESCRIPTION

EVHF920-S-00D is designed for smart power meter application with a total triple output power of 4.85W. One output with GND2 connected to L designed for the power communications (PLC) supply.

FR1 is used to protect for the component failure or some excessive short events, also it can restrain the inrush current.

To meet the EN55022 standard, X-CAP CX1 and differential mode inductor LX1 is employed to filter EMI noise.

The diode-bridge rectifier, which is composed of D3, D4, D7 and D8, transforms input AC voltage to the dc-bus voltage.

C6 and C8 are connected in series for a high input voltage energy storage, which help to reduce line noise and protect against the line surge. R2, R6, R10, R12 and R20 are employed to balance the voltage on C6 and C8, and protect the input against over voltage.

The primary RCD consists of R7, C4 and D5, and it can restrain the high voltage spike to protect the MOSFET from damage.

R15 is for switching frequency setup, which should be positioned far away from the data sampling frequency in power meter applications to avoid unwanted noise disturbance. Moreover, a low switching frequency is commonly used to get good thermal performance under high input voltage application. C19, typically 1nF, is used for double frequency mode selection.

C11 is the power supply capacitor for Vcc, and the ceramic C12 is used in parallel with C11 to decouple the voltage noise, it should be positioned to IC as close as possible.

R21, R22 are the current sense resistors with 1% tolerance for peak current setup.

The output electrolytic capacitor C1 C3 and C9 is used to satisfy the requirement for output voltage ripple.

R1 and R4 is dummy load to regulate the output voltage within designed value.

R14, R18 are configured to set the output voltage. U1, U3, R19 and C13 compose the control loop to feedback the output signal to FB pin and guarantee the quick control loop response and system stability.

Input Line wire is connected to GND2 of main output for input AC frequency sample in power meter.